TOSHIBA Field Effect Transistor Silicon P Channel Junction Type

# 2SJ103

For Audio Amplifier, Analog Switch, Constant Current and Impedance Converter Applications

- High breakdown voltage:  $V_{GDS} = 50 \text{ V}$
- High input impedance:  $I_{GSS} = 1.0 \text{ nA (max) (V}_{GS} = 30 \text{ V)}$
- Low RDS (ON): RDS (ON) = 270  $\Omega$  (typ.) (IDSS = -5 mA)
- Complimentary to 2SK246

## **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	$V_{GDS}$	50	V
Gate current	IG	-10	mA
Drain power dissipation	P <sub>D</sub>	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	<b>−55~125</b>	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

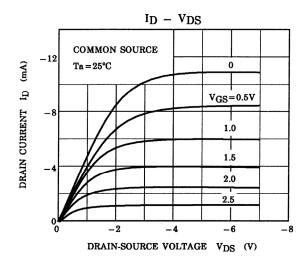
# 1. SOURCE 2. GATE 3. DRAIN JEDEC TO-92 JEITA SC-43 TOSHIBA 2-5F1C

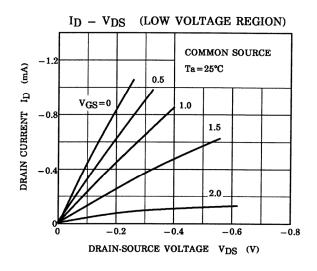
Weight: 0.21 g (typ.)

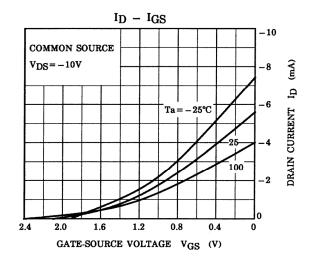
## **Electrical Characteristics (Ta = 25°C)**

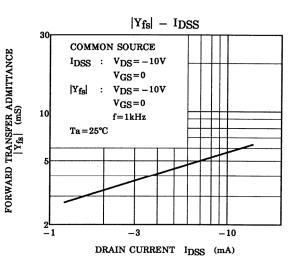
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I <sub>GSS</sub>	$V_{GS} = 30 \text{ V}, V_{DS} = 0$	_	_	1.0	nA
Gate-drain breakdown voltage	V <sub>(BR)</sub> GDS	$V_{DS} = 0$ , $I_G = 100 \mu A$	50		_	V
Drain current	I <sub>DSS</sub> (Note)	$V_{DS} = -10 \text{ V}, V_{GS} = 0$	-1.2		-14	mA
Gate-source cut-off voltage	V <sub>GS</sub> (OFF)	$V_{DS} = -10 \text{ V}, I_D = -0.1  \mu\text{A}$	0.3	_	6.0	٧
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	1.0	4.0	_	mS
Drain-source ON resistance	R <sub>DS</sub> (ON)	$V_{DS} = -10 \text{ mV}, V_{GS} = 0, I_{DSS} = -5 \text{ mA}$		270	_	Ω
Input capacitance	C <sub>iss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		18	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{DG} = -10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	_	3.6	_	pF

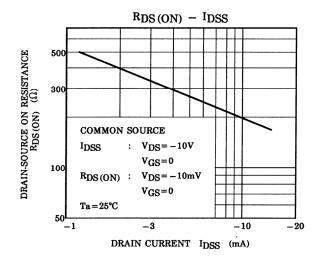
Note: I<sub>DSS</sub> classification Y: -1.2~-3.0 mA, GR: -2.6~-6.5 mA, BL: -6~-14 mA

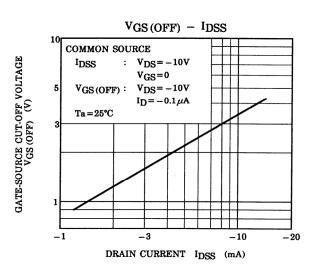




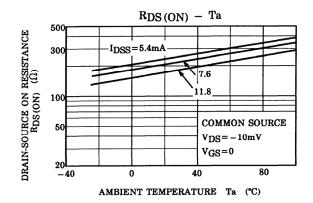


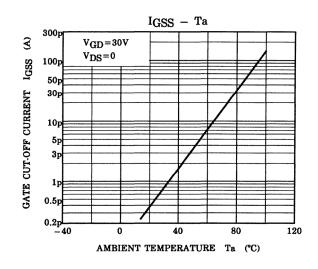


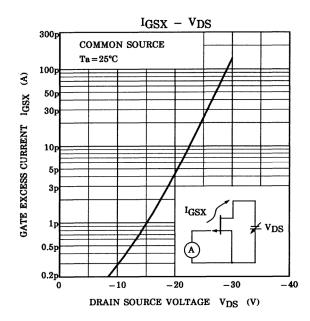


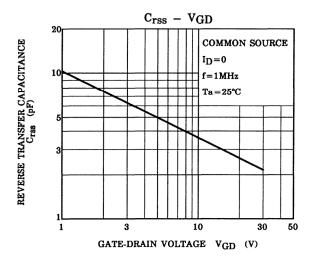


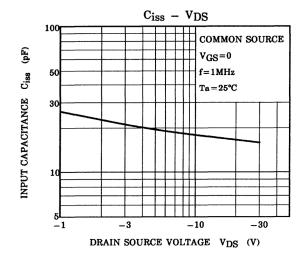
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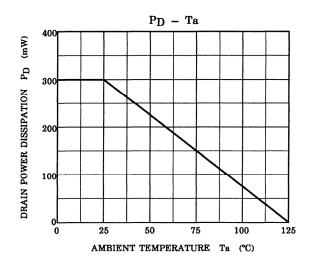












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